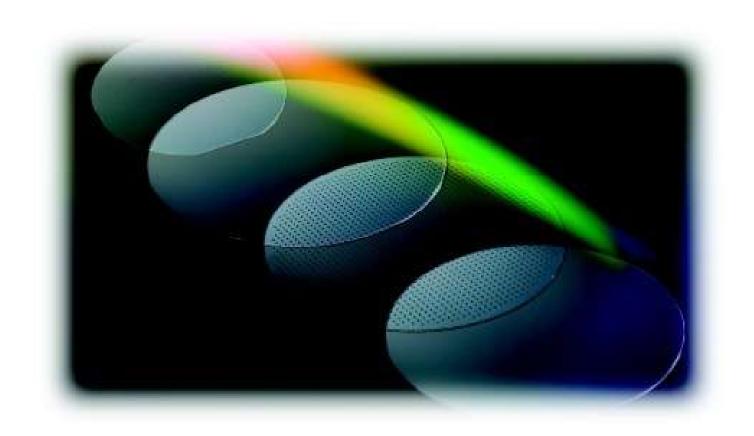
Edited: July 2025

結晶の未来を拓く Crystals for a bright future



SHINKOSHA 株式会社 信光社

STEP Substrate

To provide stable surface quality, we offer oxide single-crystal **STEP substrates** with atomically flat TERRACE and STEP defined.

This makes it a suitable option for highly reproducible, high-quality deposition.

[Features]

- Stable surface quality improves reproducibility
- AFM images of all substrates are attached of delivery
- Some Nb-doped substrates are also available



Detail site

Sapphire

Single crystal of aluminum oxide. Colorless, transparent insulator of high crystal quality and purity.



	Crystal system	Lattice constant	Size	Dopant
Al_2O_3	Trigonal (Rhombohedral)	a=0.47588nm c=1.2992nm		_
SrTiO₃	Cubic	a=0.3905nm	10×10×0.5mm	Nb:~0.05wt% (~0.1at%)
TiO ₂	Tetragonal	a=0.45935nm c=0.29580nm	15×15×0.5mm	Nb:~0.5wt% (~0.43at%)
LaAlO₃	Pseudo – cubic	a ₀ =0.379nm		-

SrTiO₃

Typical crystal of perovskite structure, ideal for research on superconductors, dielectric thin films, etc. Electrically conductive substrates doped with Nb are also available.



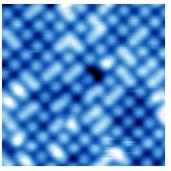
TiO₂(Rutile)

World-class crystal quality. Electrically conductive substrates doped with Nb are also available.



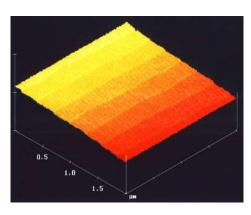


RHEED pattern of SrTiO₃ (100)

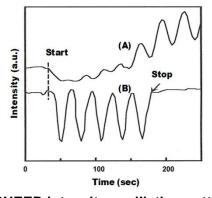


STM image of SrTiO₃ (100)

After annealing, atoms are arranged in an orderly manner on the surface (Courtesy of Hitosugi Laboratory, The University of Tokyo)



AFM Image of TiO2 STEP substrate



RHEED intensity oscillation pattern (SrTiO3 homo-epitaxial growth)
(A) Normal polish, (B) STEP surface
On a STEP substrate, crystal grows
layer by layer immediately.

All figures in graph and table are typical data (not guaranteed).

STEP Model List

Model Number	Material	Orientation	Orientation Flat	Size(mm)	Dopant	Model Type
AO-CS-10S	Sapphire	(0001)	(11-20)	10x10x0.5	_	0
AO-CS-15S	"	"	"	15x15x0.5	_	Δ
AO-AS-10S	"	(11-20)	(0001)	10x10x0.5	_	0
AO-AS-15S	"	"	"	15x15x0.5	_	Δ
AO-RS-10S	"	(01-12)	(11-20)	10x10x0.5	_	Δ
AO-RS-15S	<i>''</i>	<i>II</i>	<i>II</i>	15x15x0.5	_	Δ
ST-AS-10S	SrTiO₃	(100)	(010)	10x10x0.5	_	*
ST-AS-15S	"	<i>II</i>	<i>''</i>	15x15x0.5	_	*
ST-AS-10S-N05	"	<i>''</i>	<i>''</i>	10x10x0.5	Nb:0.05wt%	0
ST-AS-15S-N05	<i>''</i>	<i>II</i>	<i>II</i>	15x15x0.5	Nb:0.05wt%	0
TO-AS-15S	TiO2	(100)	(001)	15x15x0.5	_	Δ
TO-DS-15S	"	(110)	(110)	<i>''</i>	_	Δ
TO-AS-15S-N05	"	(100)	(001)	<i>''</i>	Nb:0.05wt%	Δ
TO-DS-15S-N05	"	(110)	(110)	<i>''</i>	Nb:0.05wt%	Δ
TO-AS-15S-N50	"	(100)	(001)	<i>II</i>	Nb:0.5wt%	Δ
TO-DS-15S-N50	<i>''</i>	(110)	(110)	<i>II</i>	Nb:0.5wt%	Δ
LA-AS-10S	LaAlO₃	(100)	(010)	10x10x0.5	_	Δ
LA-AS-15S	"	"	"	15x15x0.5	_	Δ

- Specialized package for STEP substrate
- Minimum order quantity: 5pcs
- · AFM images will be attached



Specialized case for STEP substrate

★: Planed inventory O: Standard △: Made-to-order

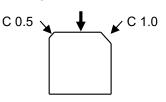
Orientation Flat

Orientation Flat
C 0.5

One-side polished type

Orientation Flat

Both-side polished type & Offset angle type



<Visual check note>
We pass over the following:

- (a) Chips within 0.2mm from the circumference of substrates
- (b) Chips on the edge strip under 1/2 size of substrate thickness
- (c) Scratches and blemish on the back side of single-side polished substrates

E-mail: sales@shinkosha.com URL: http://www.shinkosha.com/

Sapphire(α-Al₂O₃) Substrate

Sapphire is a single crystal of aluminum oxide (α -Al₂O₃). It is a colorless, transparent insulator with high crystal quality and purity. We have been dealing with sapphire for more than 75 years, and we offer our services based on our deep knowledge and rich experience. We would be delighted if this could be of help to your research.

[Features]

- Crystals with both high crystallinity and high purity
- Optically usable due to their transparency
- Stable surface quality (compatible with STEP substrates)
- · Also ideal for use as insulating plates

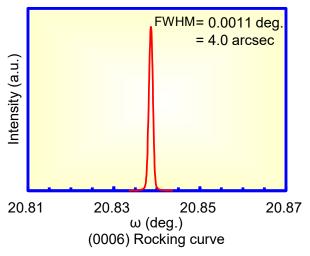


Detail site

Characteristics

Crystal system	Trigonal (Rhombohedral)
Crystal structure	Corundum
Space group	R3c
Lattice constant	a = 0.47588 nm, c = 1.2992 nm (As hexagonal)
Melting point	2040 °C
Density	3.987 g/cm ³
Dielectric constant	(//c axis) 9.41 at 30GHz
Dielectric loss	(//c axis) 3 × 10 ⁻⁵ at 30GHz
Thermal expansion	(at 200 °C, c axis) 7.63 × 10 ⁻⁶ / °C (at 200 °C, a axis) 6.93 × 10 ⁻⁶ / °C (at 1000 °C, c axis) 9.97 × 10 ⁻⁶ / °C (at 1000 °C, a axis) 8.89 × 10 ⁻⁶ / °C





Standard Specifications

Purity	>99.99%
Orientation	c(0001), a(11-20), r(01-12), m(10-10) -plane Tolerance $\pm 0.5^\circ$
Size	10×10 mm or 15×15 mm Tolerance ±0.1 mm
Thickness	0.5 mm Tolerance±0.05 mm
Polishing	One-side / Both-side
STEP	Available for :c-plane, a-plane, r-plane
Surface roughness	Ra ≦ 1.0 nm
Flatness	< 1 µm

Sapphire Model List

Size (mm)	Polishing	Surface treatment	c-plane (0001)	a-plane (11-20)	r-plane (01-12)	m-plane (10-10)
10x10x0.5	One-side	Normal	☆	0	0	0
11	Both-side	"	0	0	0	Δ
11	One-side	STEP	0	0	Δ	_
15x15x0.5	One-side	Normal	☆	Δ	Δ	Δ
11	Both-side	"	Δ	Δ	Δ	Δ
11	One-side	STEP	Δ	Δ	Δ	_

★: Planed inventory

O:Standard

 Δ : Made-to-order

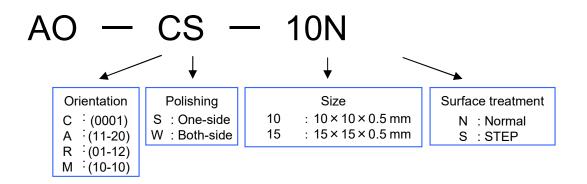
Planned inventory: Production is regularly managed to ensure prompt delivery.

(Please note that specifications may change without prior notice.)

We also accept orders for different sizes and off-spec substrates.

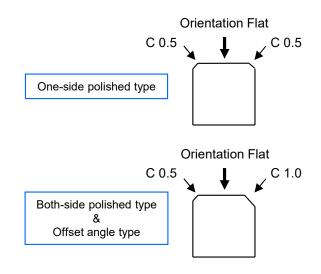
Please contact us for details.

Model Number



Orientation Flat

Substrate Orientation	Orientation Flat
c-plane (0001)	(11-20)
a-plane (11-20)	(0001)
r-plane (01-12)	(11-20)
m-plane (10-10)	(11-20)



<Visual check note>

We pass over the following:

(a) Chips within 0.2mm from the circumference of substrates

(b) Chips on the edge strip under 1/2 size of substrate thickness

(c) Scratches and blemish on the back side of single-side polished substrates

2-4-1 Kosugaya, Sakae-ku, Yokohama, 247-0007, JAPAN

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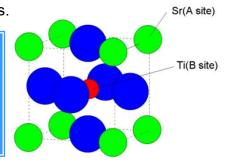
> TEL: +81-45-892-4393, FAX: +81-45-892-2986 E-mail: sales@shinkosha.com URL: http://www.shinkosha.com/

SrTiO₃(Strontium Titanate) Substrate

SrTiO₃ substrates composed of cubic crystals with a perovskite structure offer stable crystallinity and surface quality. Electrical conductivity can also be introduced through doping, making them suitable for applications such as electrical measurements.

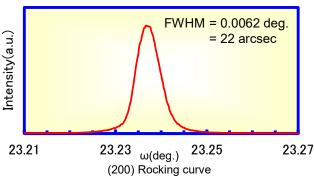
[Features]

- High-quality, high-purity crystals
- Stable surface quality (compatible with STEP substrates)
- Conductive substrates can also be achieved by doping with Nb
- Suitable for optical applications due to their transparency



SrTiO₃ Structure





[Characteristics]

Crystal system	Cubic
Crystal structure	Perovskite
Space group	Pm3m
Lattice constant	a = 0.3905 nm
Melting point	2080 ℃
Density	5.122 g/cm³ (20°C)
Dielectric constant	310 (27 °C,1MHz)
Thermal expansion	11.1 × 10 ⁻⁶ /°C(r.t. ~ 1000°C)
Phase transition	110K (tetragonal ⇔ cubic)
Refractive index	2.407 (at 589 nm)

[Standard Specifications]



Detail site

	SrTiO3	Nb:S	SrTiO3
Purity	≥99.98%		
Nb concentration	0	0.05wt% (0.1at%)	0.5wt% (1.0at%)
Resistivity	>10 ⁷ Ω•cm	7~10×10 ⁻² Ω•cm	3 ~ 7×10 ⁻³ Ω•cm
Career density	_	1∼2×10 ¹⁹ cm ⁻³	1~2×10 ²⁰ cm ⁻³
Split Angle	≦0.1°		
Orientation	(100), (110), (111) Tolerance±0.5°		
Size	10×10×0.5 mm,15×15×0.5 mm Outer size tolerance: ±0.1 mm Thickness tolerance: ±0.05 mm		
Polishing	One-side / Both-side		
STEP	Available for (100) — —		
Surface roughness	Ra≦1.0 nm,Rmax≦5.0 nm		
Flatness	$10 \times 10 \times 0.5 \text{ mm}$:≦λ , $15 \times 15 \times 0.5 \text{ mm}$: ≦1.5λ (λ=632.8 nm)		

SrTiO₃ Model list

Doning	Sizo (mm)	Surface		ace Orienta		ation	
Doping	Size (mm)	Polishing	treatment	(100)	(110)	(111)	
	10x10x0.5	One-side	Normal	*	0	*	
	<i>''</i>	Both-side	"	0	Δ	Δ	
	<i>II</i>	One-side	STEP	*	_	_	
None	<i>''</i>	Both-side	"	0	_	_	
	15x15x0.5	One-side	Normal	*	Δ	Δ	
	<i>II</i>	Both-side	"	Δ	Δ	Δ	
	<i>II</i>	One-side	STEP	*	_	_	
	10x10x0.5	One-side	Normal	*	Δ	Δ	
	<i>''</i>	Both-side	"	Δ	Δ	Δ	
Nb:0.05wt%	<i>''</i>	One-side	STEP	0	_	_	
ND.U.USW176	15x15x0.5	One-side	Normal	0	Δ	Δ	
	<i>''</i>	Both-side	"	Δ	Δ	Δ	
	<i>II</i>	One-side	STEP	0	_	_	
	10x10x0.5	One-side	Normal	*	Δ	Δ	
Nb:0.5wt%	<i>''</i>	Both-side	<i>''</i>	Δ	Δ	Δ	
เหม.บ.อพเ%	15x15x0.5	One-side	<i>''</i>	0	Δ	Δ	
	<i>II</i>	Both-side	<i>''</i>	Δ	Δ	Δ	

★: Planed inventory

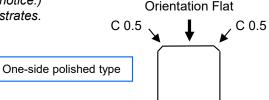
O:Standard

△: Made-to-order

Planned inventory: Production is regularly managed to ensure prompt delivery. (Please note that specifications may change without prior notice.) We also accept orders for different sizes and off-spec substrates. Please contact us for details.

Dopant

Orientation Flat



Model Number

Orientation

CT	λC	100	NIÒ	_
•	_	<u></u>	<u></u>	
G : (111)	15 : 15×	15×0.5 mm	N50 : I	Nb 0.5wt%
D : (110)	10 : 10 ×	10 × 0.5 mm		Nb 0.05wt%
A : (100)		Size	No entry : I	Non doped

Polishing S: One-side W: Both-side

Surface treatment

N: Normal S:STEP

<Visual check note>

We pass over the following:

(a) Chips within 0.2mm from the circumference of substrates

(b) Chips on the edge strip under 1/2 size of substrate thickness

(c) Scratches and blemish on the back side of single-side polished substrates

Orientation Flat
.5 C 1.0

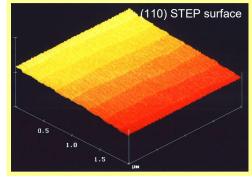
Substrate Orientation	Orientation Flat
(100)	(010)
(110)	(100)
(110)	(110)

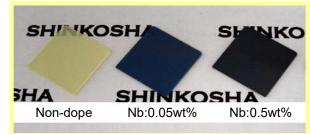
TiO₂(Rutile) Substrate

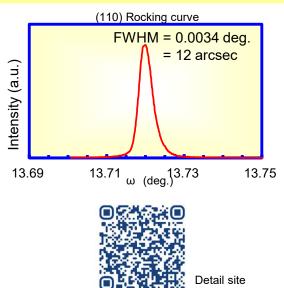
We offer rutile-type TiO₂ crystals in their high-temperature stable phase. These crystals provide stable crystallinity and surface quality, and can be made conductive through doping. We hope they will be useful for your research.

[Features]

- Available in various surface orientations of tetragonal crystals
- Stable surface quality (compatible with STEP substrates)
- Electrical conductivity can be introduced by doping with Nb
- Suitable for optical applications due to its transparency







[Characteristics]

Crystal system	Tetragonal	
Crystal structure	Rutile	
Space group	P4 ₂ /mnm	
Lattice constant	a = 0.45935 nm c = 0.29580 nm	
Melting point	1840 ℃	
Density	4.252 g/cm ³ (20°C)	
Dielectric constant	113 (1MHz)	
Thermal expansion	(// a-axis) 7.81 × 10 ⁻⁶ /°C (// c-axis) 10.1 × 10 ⁻⁶ /°C	
Band gap	3.0 eV	
Refractive index	n _o = 2.5490 n _e = 2.8226 (at 706.5nm)	

[Standard Specifications]

	TiO ₂	Nb:TiO ₂		
Nb concentration	0	0.05wt% (0.04at%)	0.5wt% (0.43at%)	
Resistivity	>10 ⁷ Ω•cm	2.5 ~ 10 Ω•cm	0.20∼0.35 Ω•cm	
Orientation	(100), (001), (110) Tolerance: ±0.5°			
Size	$10 \times 10 \times 0.5 \ \text{mm}$, $15 \times 15 \times 0.5 \ \text{mm}$ Tolerance (outside dimension): $\pm 0.1 \ \text{mm}$ Tolerance (thickness): $\pm 0.05 \ \text{mm}$			
Polishing	One-side / Both-side			
STEP	Available for (100), (110)			
Surface roughness	Ra ≦ 1.0nm , Rmax ≦ 5.0nm			
Flatness	10 × 10 × 0.5 mm :≦λ, 15 × 15 × 0.5 mm : ≦1.5λ (λ=632.8 nm)			

TiO₂ Model list

Doping Size (mm)		Polishing	Surface	Orientation		
		Polishing	treatment	(100)	(110)	(001)
10x10x0.5		One-side	Normal	*	*	*
	"	Both-side	<i>II</i>	Δ	Δ	0
None	<i>''</i>	One-side	STEP	Δ	Δ	_
None	15x15x0.5	One-side	Normal	0	0	0
	<i>''</i>	Both-side	<i>''</i>	Δ	Δ	0
	"	One-side	STEP	Δ	Δ	_
	10x10x0.5	One-side	Normal	0	0	Δ
Nb:0.05wt% // 15x15x0.5 // // //	<i>''</i>	Both-side	<i>''</i>	Δ	Δ	Δ
	"	One-side	STEP	Δ	Δ	_
	15x15x0.5	One-side	Normal	0	0	Δ
	"	Both-side	<i>''</i>	Δ	Δ	Δ
	One-side	STEP	Δ	Δ	_	
	10x10x0.5	One-side	Normal	0	0	Δ
	<i>''</i>	Both-side	<i>''</i>	Δ	Δ	Δ
Nb:0 Fud9/	<i>''</i>	One-side	STEP	Δ	Δ	_
Nb:0.5wt%	15x15x0.5	One-side	Normal	0	0	Δ
	"	Both-side	<i>''</i>	Δ	Δ	Δ
	"	One-side	STEP	Δ	Δ	_

★: Planed inventory

O: Standard

△: Made-to-order

Dopant

Orientation Flat

One-side polished type

Orientation Flat C 0.5 C 0.5

Planned inventory: Production is regularly managed to ensure prompt delivery. (Please note that specifications may change without prior notice.) We also accept orders for different sizes and off-spec substrates.

Please contact us for details.

Model Number

Polishing S: One-side W: Both-side Surface treatment N : Normal

S:STEP

Orientation			
A: (100)			
D: (110)			
C: (001)			
E:(101)			
G:(111)			

Size $10:10 \times 10 \times 0.5 \text{ mm}$ $15:15 \times 15 \times 0.5 \text{ mm}$

No entry: Non doped N05: Nb 0.05wt%

N50: Nb 0.5wt% <Visual check note> We pass over the following: (a) Chips within 0.2mm from the circumference of substrates (b) Chips on the edge strip under 1/2 size of substrate thickness

(c) Scratches and blemish on the back side of single-side polished substrates

Orientation Flat C 0.5 Both-side polished type Offset angle type

Substrate Orientation	Orientation Flat	
(100)	(001)	
(110)	(110)	
(001)	(110)	
(101)	(100)	
(111)	(110)	

LaAlO₃ (Lanthanum Aluminate) Substrate

A phase transition occurs around 420 $^{\circ}$ C, resulting in a trigonal crystal structure at room temperature. However, the material is often treated as a pseudo-cubic crystal for high-temperature applications, and is used as a substrate with a lattice constant of a = 0.379nm (cubic notation).

Due to the phase transition during cooling after crystal growth, twinning may occur in the crystal, making high crystallinity at room temperature difficult to achieve.

Nevertheless, stable surface quality (compatible with STEP substrates) can still be provided.

[Features]

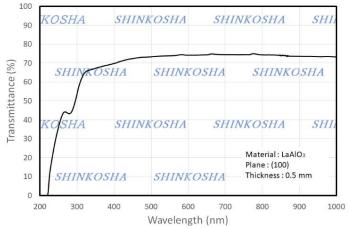
- Phase transition occurs around 420 ° C
- Stable surface quality (compatible with STEP substrates)
- Suitable for optical applications due to its transparency



Detail site



Transmittance of LaAlO3 substrate



[Characteristics]

Crystal system	Trigonal (Pseudo-cubic) *		
Crystal structure	Pseudo-Perovskite		
Space group	R3c		
Lattice constant	a ₀ = 0.379 nm (Pseudo-cubic)		
Melting point	2100 ℃		
Density	6.52 g/cm ³		
Dielectric constant	15∼22 (27°C,1MHz)		
Thermal expansion	12.6 × 10 ^{−6} /°C		
Phase transition temperature	Approx. 420 °C (Trigonal ⇔ Cubic)		
Twin crystal	Generated by phase transition		

[Standard Specifications]

Orientation	(100),(110) Tolerance±0.5° (in Pseudo-cubic)	
Size	$10 \times 10 \times 0.5 \text{ mm}$, $15 \times 15 \times 0.5 \text{ mm}$ Tolerance (outside dimension) : $\pm 0.1 \text{ m}$ Tolerance (thickness) : $\pm 0.05 \text{ mm}$	
Polishing	One-side / Both-side	
STEP	Available for (100)	
Surface roughness	Ra ≦1.0nm,Rmax ≦5.0nm	

If you are looking for other specs, please contact us.

*LaAlO₃ is a trigonal crystal (a=0.5357nm, α =60.1°) accurately, but it is treated as a pseudo-cubic or hexagonal crystal generally.

LaAlO₃ Model list

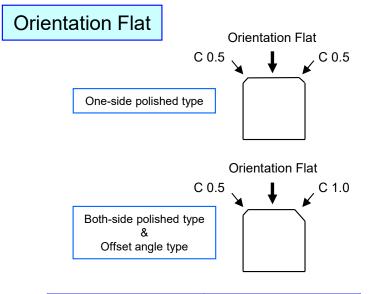
Siza (mm)	Deliahing	Surface	Orientation		
Size (mm)	Polishing	treatment	(100)	(110)	
10x10x0.5mm	One-side	Normal	0	Δ	
II	Both-side	11	0	Δ	
II	One-side STEP		Δ	_	
15x15x0.5mm	One-side	One-side Normal		Δ	
II	Both-side	II	Δ	Δ	
II	One-side	STEP	Δ	_	

O:Standard

△: Made-to-order

If you are looking for different sizes (up to φ 2 in), offset angle type and others, please contact us. *Minimum order for STEP model, made-to-order model and special model: 5pcs

Model Number Polishing Surface treatment S: One-side N : Normal W: Both-side S:STEP Orientation Size A: (100) $10:10 \times 10 \times 0.5 \, \text{mm}$ D: (110) $15:15\times15\times0.5 \,\mathrm{mm}$



Substrate Orientation	Orientation Flat
(100)	(010)
(110)	(100)

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E-mail: sales@shinkosha.com URL: http://www.shinkosha.com/

<Visual check note>

We pass over the following:
(a) Chips within 0.2mm from the circumference of substrates

⁽b) Chips on the edge strip under 1/2 size of substrate thickness

⁽c) Scratches and blemish on the back side of single-side polished substrates

NdGaO₃ (Neodymium Gallate) Substrate

Although it has an orthorhombic crystal structure, the Ga–Ga interatomic distance is approximately 0.386 nm on the (110) and (001) planes, making it widely used as a substrate with a lattice constant intermediate between SrTiO₃ and LaAlO₃.

High-quality crystals can be reliably obtained through the Czochralski (CZ) method using a stoichiometric melt.

[Features]

- Lattice constant intermediate between SrTiO₃ and LaAlO₃ substrates
- High-quality crystals can be stably obtained
- In-house crystal production enables excellent QCD (Quality, Cost, Delivery) performance



FWHM = 0.0049 deg. = 18 arcsec 23.53 23.55 ω (deg.) (004) Rocking curve



[Characteristics]

Crystal system	Orthorhombic	
Crystal structure	Perovskite	
Lattice constant	a = 0.5431 nm b = 0.5499 nm c = 0.7710 nm	
Melting point	1650 °C	
Density	7.56 g/cm³	
Dielectric constant	20∼25 (27°C,1MHz)	
Thermal expansion	10 × 10 ⁻⁶ /°C	

[Standard Specifications]

Orientation	(100),(001),(110),(011) Tolerance : ±0.5°		
Size	10×10×0.5mm 15×15×0.5mm Tolerance (outside dimension):±0.1 mm Tolerance (thickness):±0.05 mm		
Polishing	One-side / Both-side		
Surface roughness	Ra ≦1.0nm,Rmax ≦5.0nm		
Flatness	$10 \times 10 \times 0.5$ mm: ≤ λ $15 \times 15 \times 0.5$ mm: ≤ 1.5λ (λ=632.8nm)		

If you are looking for other specs, please contact us.

NdGaO₃ Model list

Size (mm)	Daliahing	Orientation			
	Polishing	(100)	(001)	(110)	(011)
10x10x0.5mm	One-side	0	0	*	Δ
<i>11</i>	Both-side	Δ	Δ	Δ	Δ
15x15x0.5mm	One-side	Δ	Δ	Δ	Δ
11	Both-side	Δ	Δ	Δ	Δ

★: Planed inventory

O: Standard

△: Made-to-order

Planned inventory: Production is regularly managed to ensure prompt delivery. (Please note that specifications may change without prior notice.) We also accept orders for different sizes and off-spec substrates. Please contact us for details.

Model Number Orientation Flat Orientation Flat C 0.5 C 0.5 Polishing Surface treatment One-side polished type S : One-side N: Normal W: Both-side Orientation Flat NGO -C 1.0 C 0.5 Both-side polished type Orientation Size Offset angle type $10:10 \times 10 \times 0.5 \text{ mm}$ A: (100) $15:15 \times 15 \times 0.5 \, \text{mm}$ C: (001) D: (110) Substrate **Orientation Flat** F: (011) Orientation (100)(001)

<Visual check note>

We pass over the following:

(a) Chips within 0.2mm from the circumference of substrates

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(b) Chips on the edge strip under 1/2 size of substrate thickness

(c) Scratches and blemish on the back side of single-side polished substrates

(001)(100)(001)(110)(011)(001)

2-4-1 Kosugaya, Sakae-ku, Yokohama, 247-0007, JAPAN

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Oxide Single Crystal Substrate

We offer a variety of oxide single-crystal substrates suitable for epitaxial growth.

For details on sapphire, SrTiO₃, rutile, LaAlO₃, and NdGaO₃, please refer to the individual product catalogs.



Detail site

[Characteristics] (Reference data)

Crystal	MgO	YSZ	LSAT	MgAl ₂ O ₄
Crystal system	Cubic	Cubic	Cubic	Cubic
Crystal structure	NaCl	CaF ₂	Perovskite	Spinel
Lattice constant	a = 0.4213 nm	a = 0.5139 nm	a = 0.7736 nm	a = 0.8083 nm
Melting point	2800 ℃	2500 °C	1840 °C	2130 ℃
Density	3.59 g/cm ³	6.05 g/cm ³	6.79 g/cm ³	3.64 g/cm ³
Thermal expansion	13.5x10 ⁻⁶ /°C	10.3x10 ⁻⁶ /°C	10x10 ⁻⁶ /°C	7.5x10 ⁻⁶ /°C
Dielectric constant	10	27	22	_

[Standard Specifications]

Orientation tolerance	±0.5°	
Size	$10 \times 10 \times 0.5 \text{mm}$, $15 \times 15 \times 0.5 \text{mm}$ (max : φ2in) Outer size tolerance : $\pm 0.1 \text{mm}$ Thickness tolerance : $\pm 0.05 \text{mm}$	
Surface roughness	Ra ≦1.0nm,Rmax ≦5.0nm	
Flatness	10 × 10 × 0.5mm : ≦λ , 15 × 15 × 0.5mm : ≦1.5λ (λ=632.8nm) ※ Excluding MgO and MgAl ₂ O ₄	

^{*}This table is made for a general specification. Since it may differ from above specifications depending on materials and orientations, please ask us for the details.



Orientation	Orientation flat	Size	One-side polishing	Both-side polishing
(100)	(010)	10x10x0.5mm	0	0
<i>''</i>	"	15x15x0.5mm	0	Δ



Yttria Stabilized Zirconia (Y₂O₃≒10mol%)

Orientation	Orientation flat	Size	One-side polishing	Both-side polishing
(100)	(010)	10x10x0.5mm	0	0
11	11	15x15x0.5mm	0	Δ
(111)	(110)	10x10x0.5mm	*	0

[Note] YSZ is not able to be exported from Japan

★:Planed inventory

O: Standard

△: Made-to-order

LSAT

 $(\mathsf{La}_{0.3}\mathsf{Sr}_{0.7})(\mathsf{AI}_{0.65}\mathsf{Ta}_{0.35})\mathsf{O}_3$

Orientation	Orientation flat	Size	One-side polishing	Both-side polishing
(100)	(010)	10x10x0.5mm	☆	Δ
11	11	15x15x0.5mm	0	Δ

MgAl₂O₄

Spinel

Orientation	Orientation flat	Size	One-side polishing	Both-side polishing
(100)	(010)	10x10x0.5mm	0	Δ
(111)	(110)	10x10x0.5mm	Δ	Δ

★: Planed inventory

O:Standard

△: Made-to-order

Planned inventory: Production is regularly managed to ensure prompt delivery.

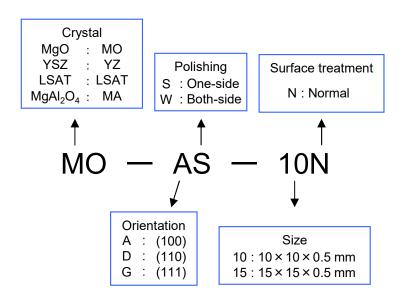
(Please note that specifications may change without prior notice.)

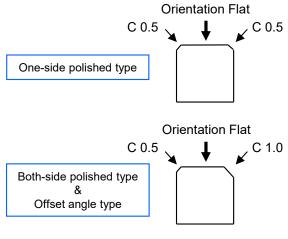
We also accept orders for different sizes and off-spec substrates.

Please contact us for details.

Model Number

Orientation Flat





<Visual check note>

We pass over the following:

(a) Chips within 0.2mm from the circumference of substrates

(b) Chips on the edge strip under 1/2 size of substrate thickness

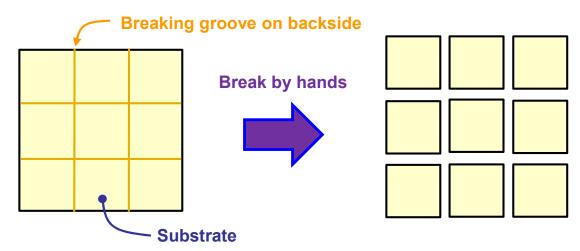
(c) Scratches and blemish on the back side of single-side polished substrates

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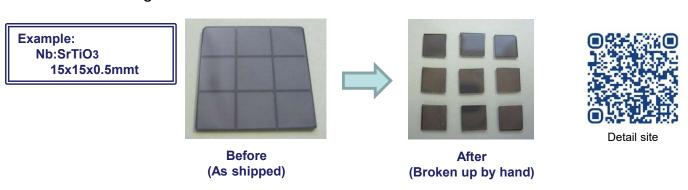
E-mail : sales@shinkosha.com URL : http://www.shinkosha.com/

Breakable Substrates

To facilitate easy division when using our single-crystal substrates, we offer substrates with pre-formed breaking grooves on the backside.



Since breaking grooves are pre-formed, the substrate can be cleanly and efficiently divided by hand—just like breaking a chocolate bar—without the need for diamond cutters or cutting machines.

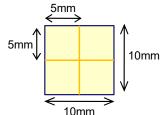


Standard model

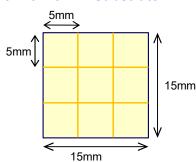
Material	Substrate size	Breakup pattern
SrTiO3		
TiO2	0	14 segments of
LaAlO3	①10x10 mm	5x5 mm
LSAT	②15x15 mm	29 segments of
YSZ	9.52.10	5x5 mm
MgAl2O4		

^{*}Please feel free to ask us for other breakup patterns.

¹ For 10x10 mm substrate



2 For 15x15 mm substrate



<Visual check note>

We pass over the following:

⁽a) Chips within 0.2mm from the circumference of substrates

⁽b) Chips on the edge strip under 1/2 size of substrate thickness

⁽c) Scratches and blemish on the back side of single-side polished substrates

⁽d) Chips from grooving process on the back side of substrates

Operating Suggestions for Oxide Single Crystal Substrates

(1) Guaranteed figures

	Guaranteed figures
Size tolerance	±0.1 mm
Thickness tolerance	±0.05 mm
Orientation tolerance 1)	±0.5°
Orientation flat tolerance	±1.0°
Flatness ₂₎	$10 \times 10 \times 0.5$ mm substrate : ≤ λ $15 \times 15 \times 0.5$ mm substrate : ≤ 1.5λ (λ=632.8nm)

- 1) STEP substrates: ±0.3°, OFF substrates: Designed OFF angle ±0.1°
- 2) Excluding LaAlO3, MgO and MgAl2O4 substrates

(2) Cleaning of substrates

· Normal substrates:

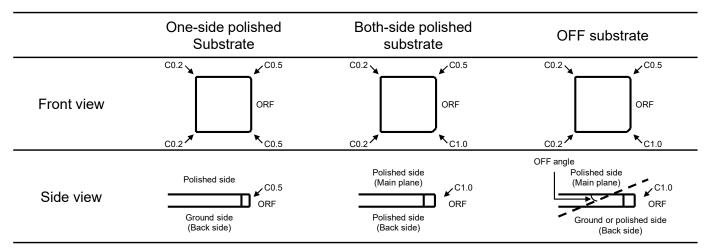
Standard cleaning is done, but we recommend an additional cleaning by yourself.

STEP substrates:

For $10 \times 10 \times 0.5$ mm and $15 \times 15 \times 0.5$ mm size substrates, precision cleaning and special packing are done. For other sizes, standard cleaning and packing are done. We recommend an additional cleaning by yourself.

(3) Orientation Flat (ORF)

Standard size substrates have "Orientation Flat Markings" (size C0.5 or C1.0) at the corners as below.



(4) Main plane

 We can only assure the quality of "Main plane" for both-side polished substrates (including STEP substrates) due to the nature of our manufacturing process. Please use "Main plane" for your work.

(5) Visual check note

- We pass over the following:
 - (a) Chips within 0.2mm from the circumference of substrates
 - (b) Chips on the edge strip under 1/2 size of substrate thickness
 - (c) Scratches and blemish on the back side of single-side polished substrates

(6) Crystallinity

- LaAlO3 substrates contain twins.
- SrTiO₃, TiO₂, MgO and YSZ substrates may contain small sub-grain boundaries due to the nature of their manufacturing process. It may be shown in multi peaks in their X-ray rocking curve.

If you have any questions, please feel free to contact us.

SHINKOSHA 株式会社 信光社